

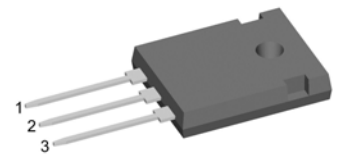
**HiPerFRED<sup>2</sup>**

$$\begin{aligned} V_{RRM} &= 200\text{ V} \\ I_{FAV} &= 2 \times 15\text{ A} \\ t_{rr} &= 35\text{ ns} \end{aligned}$$

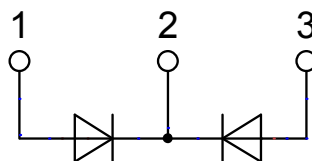
High Performance Fast Recovery Diode  
Low Loss and Soft Recovery  
Common Cathode

Part number

**DPG30C200HB**



Backside: cathode

**Features / Advantages:**

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low  $I_{rm}$ -values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low  $I_{rm}$  reduces:
  - Power dissipation within the diode
  - Turn-on loss in the commutating switch

**Applications:**

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

**Package: TO-247**

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

| Fast Diode |                                              |                                                                                  |                                | Ratings                        |      |      |               |
|------------|----------------------------------------------|----------------------------------------------------------------------------------|--------------------------------|--------------------------------|------|------|---------------|
| Symbol     | Definition                                   | Conditions                                                                       |                                | min.                           | typ. | max. | Unit          |
| $V_{RSM}$  | max. non-repetitive reverse blocking voltage | $T_{VJ} = 25^{\circ}\text{C}$                                                    |                                |                                |      | 200  | V             |
| $V_{RRM}$  | max. repetitive reverse blocking voltage     | $T_{VJ} = 25^{\circ}\text{C}$                                                    |                                |                                |      | 200  | V             |
| $I_R$      | reverse current, drain current               | $V_R = 200\text{ V}$                                                             | $T_{VJ} = 25^{\circ}\text{C}$  |                                |      | 1    | $\mu\text{A}$ |
|            |                                              | $V_R = 200\text{ V}$                                                             | $T_{VJ} = 150^{\circ}\text{C}$ |                                |      | 0.08 | mA            |
| $V_F$      | forward voltage drop                         | $I_F = 15\text{ A}$                                                              | $T_{VJ} = 25^{\circ}\text{C}$  |                                |      | 1.25 | V             |
|            |                                              | $I_F = 30\text{ A}$                                                              |                                |                                |      | 1.50 | V             |
|            |                                              | $I_F = 15\text{ A}$                                                              | $T_{VJ} = 150^{\circ}\text{C}$ |                                |      | 1.00 | V             |
|            |                                              | $I_F = 30\text{ A}$                                                              |                                |                                |      | 1.27 | V             |
| $I_{FAV}$  | average forward current                      | $T_C = 145^{\circ}\text{C}$<br>rectangular $d = 0.5$                             | $T_{VJ} = 175^{\circ}\text{C}$ |                                |      | 15   | A             |
| $V_{FO}$   | threshold voltage                            | } for power loss calculation only                                                |                                | $T_{VJ} = 175^{\circ}\text{C}$ |      | 0.69 | V             |
| $r_F$      | slope resistance                             |                                                                                  |                                |                                |      | 17.3 | m $\Omega$    |
| $R_{thJC}$ | thermal resistance junction to case          |                                                                                  |                                |                                |      | 1.7  | K/W           |
| $R_{thCH}$ | thermal resistance case to heatsink          |                                                                                  |                                |                                | 0.25 |      | K/W           |
| $P_{tot}$  | total power dissipation                      | $T_C = 25^{\circ}\text{C}$                                                       |                                |                                |      | 90   | W             |
| $I_{FSM}$  | max. forward surge current                   | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}; V_R = 0\text{ V}$               | $T_{VJ} = 45^{\circ}\text{C}$  |                                |      | 240  | A             |
| $C_J$      | junction capacitance                         | $V_R = 150\text{ V}$ $f = 1\text{ MHz}$                                          | $T_{VJ} = 25^{\circ}\text{C}$  |                                | 20   |      | pF            |
| $I_{RM}$   | max. reverse recovery current                | $I_F = 15\text{ A}; V_R = 130\text{ V}$<br>$-di_F/dt = 200\text{ A}/\mu\text{s}$ | $T_{VJ} = 25^{\circ}\text{C}$  |                                | 3    |      | A             |
|            |                                              |                                                                                  | $T_{VJ} = 125^{\circ}\text{C}$ |                                | 6.5  |      | A             |
|            |                                              |                                                                                  | $T_{VJ} = 25^{\circ}\text{C}$  |                                | 35   |      | ns            |
|            |                                              |                                                                                  | $T_{VJ} = 125^{\circ}\text{C}$ |                                | 55   |      | ns            |
| $t_{rr}$   | reverse recovery time                        |                                                                                  |                                |                                |      |      |               |

| Package TO-247 |                              |                            | Ratings |      |      |      |
|----------------|------------------------------|----------------------------|---------|------|------|------|
| Symbol         | Definition                   | Conditions                 | min.    | typ. | max. | Unit |
| $I_{RMS}$      | RMS current                  | per terminal <sup>1)</sup> |         |      | 50   | A    |
| $T_{VJ}$       | virtual junction temperature |                            | -55     |      | 175  | °C   |
| $T_{op}$       | operation temperature        |                            | -55     |      | 150  | °C   |
| $T_{stg}$      | storage temperature          |                            | -55     |      | 150  | °C   |
| Weight         |                              |                            |         | 6    |      | g    |
| $M_D$          | mounting torque              |                            | 0.8     |      | 1.2  | Nm   |
| $F_C$          | mounting force with clip     |                            | 20      |      | 120  | N    |

### Product Marking



### Part number

D = Diode  
 P = HiPerFRED  
 G = extreme fast  
 30 = Current Rating [A]  
 C = Common Cathode  
 200 = Reverse Voltage [V]  
 HB = TO-247AD (3)

| Ordering | Part Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-------------|--------------------|---------------|----------|----------|
| Standard | DPG30C200HB | DPG30C200HB        | Tube          | 30       | 505797   |

| Similar Part | Package              | Voltage class |
|--------------|----------------------|---------------|
| DPG30C200PB  | TO-220AB (3)         | 200           |
| DPG30C200PC  | TO-263AB (D2Pak) (2) | 200           |

### Equivalent Circuits for Simulation

\* on die level

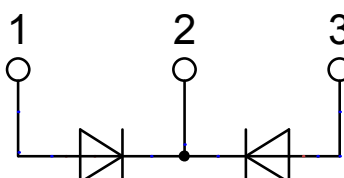
$T_{VJ} = 175\text{ °C}$

|                    |                    |      |                   |
|--------------------|--------------------|------|-------------------|
|                    |                    |      | <b>Fast Diode</b> |
| $V_{0\text{ max}}$ | threshold voltage  | 0.69 | V                 |
| $R_{0\text{ max}}$ | slope resistance * | 14.7 | mΩ                |

## Outlines TO-247



| Sym. | Inches |       | Millimeter |       |
|------|--------|-------|------------|-------|
|      | min.   | max.  | min.       | max.  |
| A    | 0.185  | 0.209 | 4.70       | 5.30  |
| A1   | 0.087  | 0.102 | 2.21       | 2.59  |
| A2   | 0.059  | 0.098 | 1.50       | 2.49  |
| D    | 0.819  | 0.845 | 20.79      | 21.45 |
| E    | 0.610  | 0.640 | 15.48      | 16.24 |
| E2   | 0.170  | 0.216 | 4.31       | 5.48  |
| e    | 0.215  | BSC   | 5.46       | BSC   |
| L    | 0.780  | 0.800 | 19.80      | 20.30 |
| L1   | -      | 0.177 | -          | 4.49  |
| Ø P  | 0.140  | 0.144 | 3.55       | 3.65  |
| Q    | 0.212  | 0.244 | 5.38       | 6.19  |
| S    | 0.242  | BSC   | 6.14       | BSC   |
| b    | 0.039  | 0.055 | 0.99       | 1.40  |
| b2   | 0.065  | 0.094 | 1.65       | 2.39  |
| b4   | 0.102  | 0.135 | 2.59       | 3.43  |
| c    | 0.015  | 0.035 | 0.38       | 0.89  |
| D1   | 0.515  | -     | 13.07      | -     |
| D2   | 0.020  | 0.053 | 0.51       | 1.35  |
| E1   | 0.530  | -     | 13.45      | -     |
| Ø P1 | -      | 0.29  | -          | 7.39  |



## Fast Diode

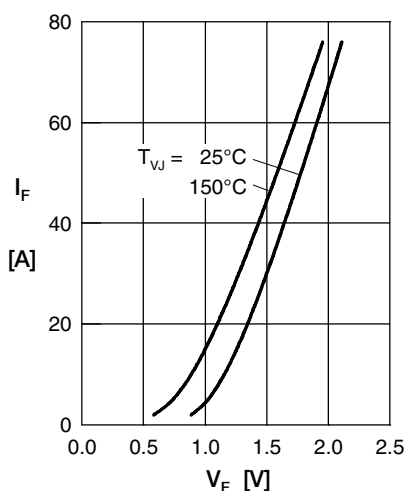


Fig. 1 Forward current  $I_F$  versus  $V_F$

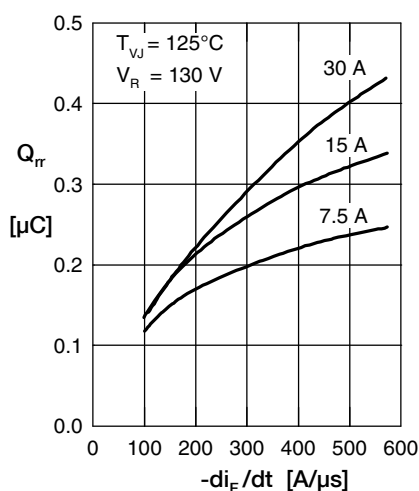


Fig. 2 Typ. reverse recov. charge  $Q_{rr}$  versus  $-di_F/dt$

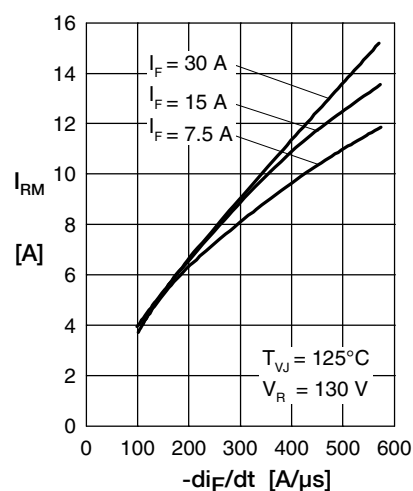


Fig. 3 Typ. peak reverse current  $I_{RM}$  versus  $-di_F/dt$

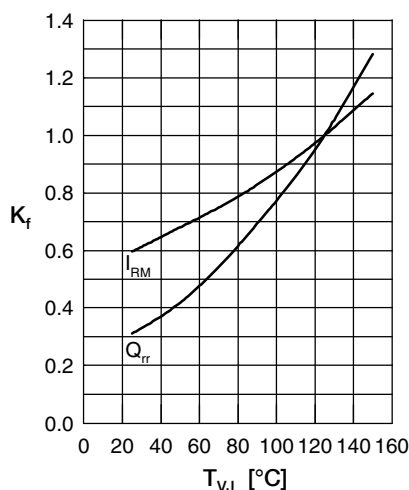


Fig. 4 Typ. dynamic parameters  $Q_{rr}$ ,  $I_{RM}$  versus  $T_{VJ}$

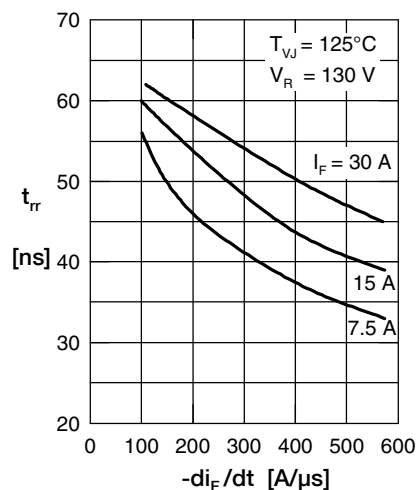


Fig. 5 Typ. recovery time  $t_{rr}$  versus  $-di_F/dt$

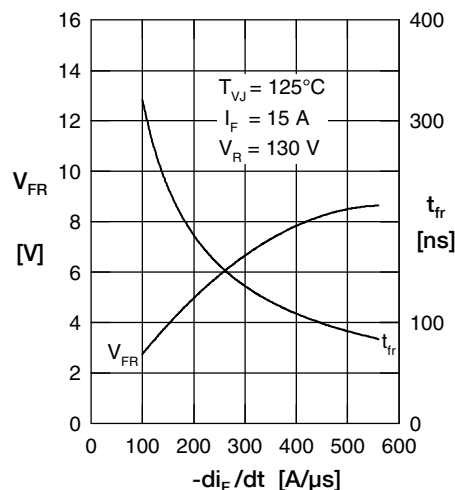


Fig. 6 Typ. peak forward voltage  $V_{FR}$  and  $t_{rr}$  versus  $di_F/dt$

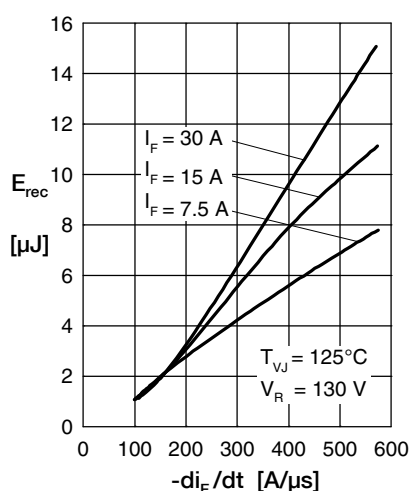


Fig. 7 Typ. recovery energy  $E_{rec}$  versus  $-di_F/dt$

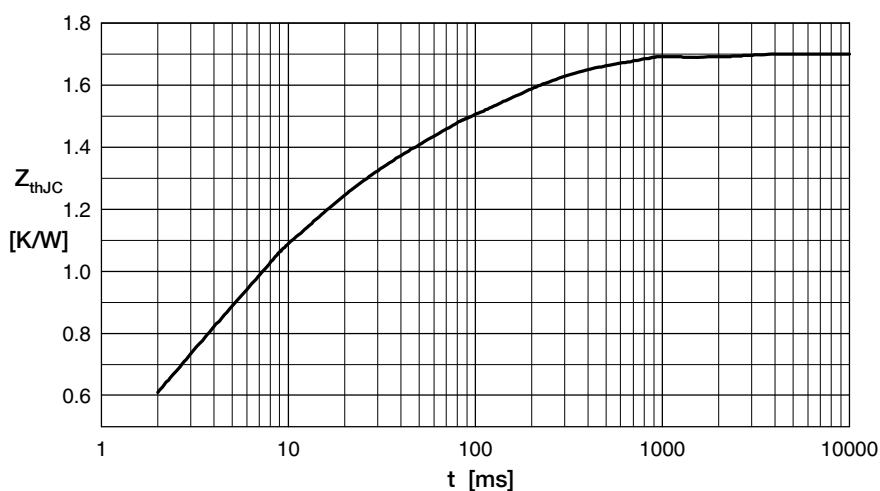


Fig. 8 Transient thermal resistance junction to case